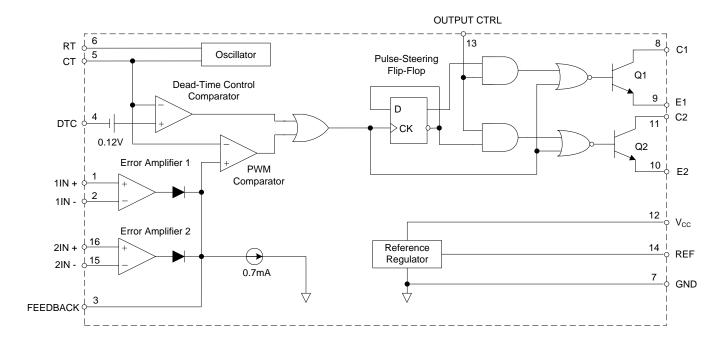


Output Function Table

Signal for Output Control	Output Function
$V_{I} = GND$	Single-ended or parallel output
$V_{I} = V_{REF}$	Normal push-pull operation

Functional Block Diagram





Absolute Maximum Ratings (Note 3)

Symbol	Parameter	Rating	Unit
V _{CC}	Supply Voltage (Note 4)	40	V
Vı	Amplifier Input Voltage	-0.3 to V _{CC} + 0.3	V
Vo	Collector Output Voltage	40	V
Io	Collector Output Current	250	mA
$R_{\theta JA}$	Package Thermal Impedance (Note 5)	73	°C/W
_	Lead Temperature 1.6mm from case for 10 seconds	+260	°C
T _{STG}	Storage Temperature Range	-65 to +150	°C
ESD Rating (Machine Model)		200	V

Notes: 3. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit
V _{cc}	Supply Voltage	7	15	36	V
V_{C1}, V_{C2}	Collector Output Voltage	_	30	36	V
I _{C1} , I _{C2}	Collector Output Current (Each Transistor)	-	-	200	mA
Vı	Amplifier Input Voltage	0.3	_	V _{CC} -2	V
I _{FB}	I _{FB} Current Into Feedback Terminal I _{REF} Reference Output Current		_	0.3	mA
I _{REF}			-	10	mA
Ст	Timing Capacitor	0.00047	0.001	10	μF
R _T	R _T Timing Resistor f _{OSC} Oscillator Frequency - PWM Input Voltage (Pin 3, 4, 14)		30	500	kΩ
f _{osc}			40	200	kHz
_			-	5.3	V
T _A	Operating Free-Air Temperature	-40	_	+85	°C

^{4.} All voltage values are with respect to the network ground terminal.

^{5.} Maximum power dissipation is a function of $T_J(max)$, $R_{\theta JA}$ and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/R_{\theta JA}$. Operating at the absolute maximum T_J of +150°C can affect reliability.

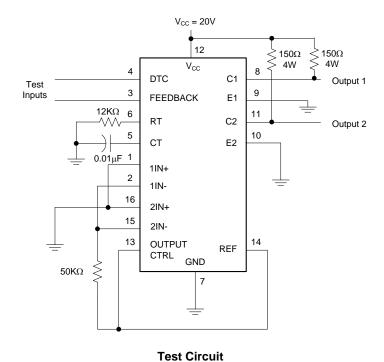


Electrical Characteristics (@V_{CC}=20V, T_A= +25°C, f=10kHz, unless otherwise specified.)

Symbol	Param	neters	Conditions	Min	Тур	Max	Unit	
Reference Se	ection		<u> </u>	1	, ,,,	1	1	
			I _{REF} =1mA	4.90	4.95	5.0	V	
V_{REF}	Output Reference Voltage	е	I_{REF} =1mA, T_{A} = -40 to +85°C	4.85	4.95	5.05	V	
R _{LINE}	Line Regulation		V _{CC} = 7V to 36V	_	2	25	mV	
R _{LOAD}	Load Regulation		I _{REF} =1mA to 10mA	_	1	15	mV	
I _{SC}	Short-Circuit Output Cur	rent	V _{REF} = 0V	10	35	50	mA	
Oscillator Sec	ction		- 1	•				
			C_T =0.001 μ F, R_T =30 $K\Omega$	_	40	_		
f _{osc}	Oscillator Frequency		$C_T=0.01\mu F, R_T=12K\Omega$	9.2	10	10.8	kHz	
TOSC	Oscillator Frequency		C_T =0.01 μ F, R_T =12 $K\Omega$, T_A = -40 to +85 $^{\circ}$ C	9.0	_	12	KIIZ	
Δf /ΔΤ	Frequency Change with	Temperature	$C_T=0.01\mu F, R_T=12K\Omega,$ $T_A=-40 \text{ to } +85^{\circ}C$	_	_	1	%	
Dead-Time Co	ontrol Section							
I _{BIAS}	Input Bias Current		$V_{CC}=15V$, V4= 0 to 5.25V	_	-2	-10	μΑ	
D(MAX)	Maximum Duty Cycle		V _{CC} =15V, V4= 0V, Pin 13= V _{REF}	45	_	_	%	
V _{ITH} Input Threshold Voltage			Zero Duty Cycle	_	3	3.3		
			Maximum Duty Cycle	0	_	_	V	
Error-Amplific	er Section							
V_{10}	Input Offset Voltage		V3 = 2.5V	_	2	10	mV	
I _{IO}	Input Offset Current		V3 = 2.5V	_	25	250	nA	
I _{BIAS}	Input Bias Current		V3 = 2.5V	_	0.2	1	μΑ	
V_{CM}	Common-Mode Input Voltage Range		V _{CC} =7V to 36V	-0.3	_	V _{cc} -2	V	
G_{VO}	Open-Loop Voltage Gain		$V_0 = 0.5V$ to 3.5V	70	95	_	dB	
BW	Unity-Gain Bandwidth		-	_	650	_	kHz	
CMRR	Common-Mode Rejection Ratio		-	65	80	_	dB	
I _{SINK}	Output Sink Current (Fe	edback)	$V_{ID} = -15 \text{mV to } -5 \text{V}, \text{ V3} = 0.7 \text{V}$	-0.3	-0.7	_	mA	
I _{SOURCE}	Output Source Current (Feedback)	V_{ID} =15mV to 5V, V3 = 3.5V	2	-	_	mA	
PWM Compar	rator Section							
V_{ITH}	Input Threshold Voltage		Zero duty cycle	-	4	4.5	V	
I _{SINK}	Input Sink Current		V3 = 0.7V	-0.3	-0.7	_	mA	
Output Section	on							
V _{CE} (SAT)	AT) Output Seturation	Common Emitter	V _E = 0V, I _C =200mA	_	1.1	1.3		
V _{CC} (SAT)	Output Saturation Voltage Emitter Follower		$V_{CC} = 15V$, $I_E = -200$ mA	-	1.5	2.5	V	
I _C (OFF)	Collector Off-State Current		$V_{CE} = 36V, V_{CC} = 36V$	_	2	100	μΑ	
I _E (OFF)			$V_{CC} = V_C = 36V, V_E = 0$	_	-	-100	μΑ	
Total Device								
I _{cc}	Supply Current		Pin 6 = V _{REF} , V _{CC} =15V	_	6	10	mA	
Output Switch	hing Characteristics							
t _R	Rise Time		Common Emitter Common Collector	_	100	200	ns	
t _F	Fall Time		Common Emitter Common Collector	_	25	100	ns	



Parameter Measurement Information



Voltage at C1 $V_{\text{CC}} \\$ 0V $V_{\text{CC}} \\$ Voltage at C2 0V Voltage Threshold Voltage DTC 0V Threshold Voltage -**FEEDBACK** 0.7V - MAX **Duty Cycle**

Figure 1. Operational Test Circuit and Waveforms

Voltage Waveforms

July 2015



Parameter Measurement Information (Cont.)

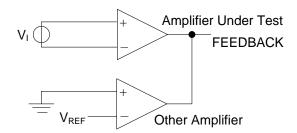
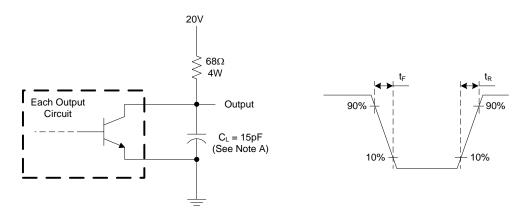
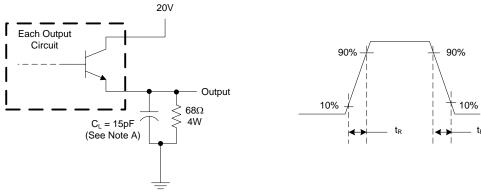


Figure 2. Error Amplifier Characteristics



Note A: C_L includes probe and jig capacitance.

Figure 3. Common-Emitter Configuration



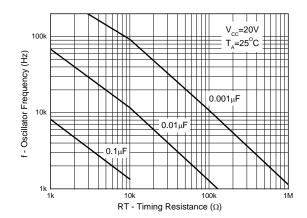
Note A: C_L includes probe and jig capacitance.

Figure 4. Emitter-Follower Configuration

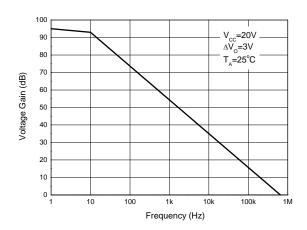


Performance Characteristics

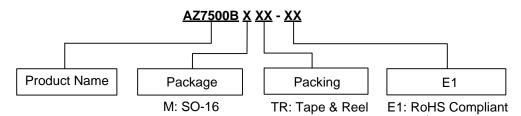
Oscillator Frequency vs. RT and CT



Error Amplifier Small-Signal Voltage Gain vs. Frequency



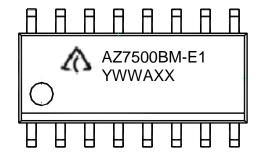
Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing
SO-16	-40 to +85°C	AZ7500BMTR-E1	AZ7500BM-E1	4000/Tape and Reel

Marking Information

(Top View)



First Line: Logo and Marking ID (See Ordering Information) Second Line: Date Code

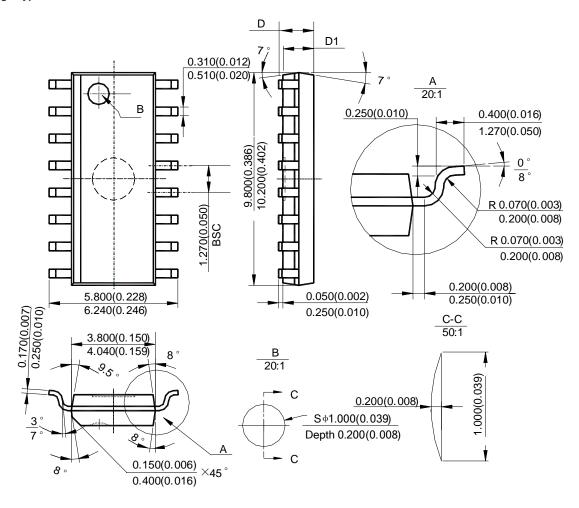
Y: Year

WW: Work Week of Molding A: Assembly House Code XX: 7th and 8th Digits of Batch No.



Package Outline Dimensions (All dimensions in mm(inch).)

(1) Package Type: SO-16



Note: Eject hole, oriented hole and mold mark is optional.

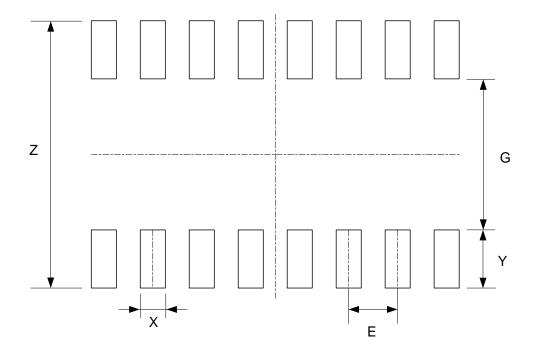
Symbol		D			D1			
Cymbol	min(mm)	max(mm)	min(inch)	max(inch)	min(mm)	max(mm)	min(inch)	max(inch)
Option1	1.350	1.750	0.053	0.069	1.250	1.650	0.049	0.065
Option2	-	1.260	-	0.050	1.020	-	0.040	-

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Suggested Pad Layout

(1) Package Type: SO-16



Dimensions	Z	G (see als)	X (22.22) (((2.24)	Y	E (22.22) (((2.24))
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	1.270/0.050



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